

# **ECE 65: Components & Circuits Lab**

## **Lecture 11**

### **BJT circuits**

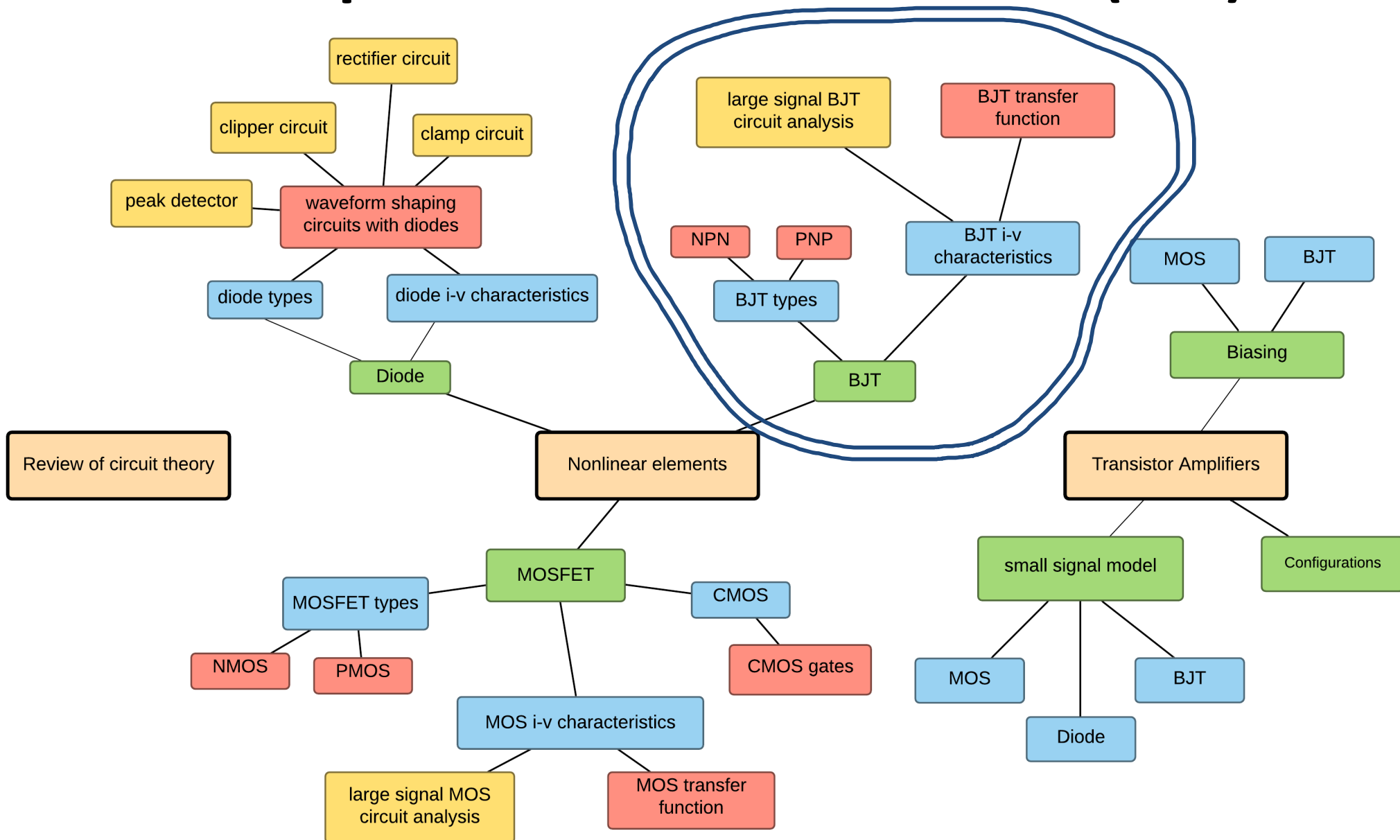
Reference notes: sections 3.2

Sedra & Smith (7<sup>th</sup> Ed): sections 6.1-6.3

Saharnaz Baghdadchi

# Course map

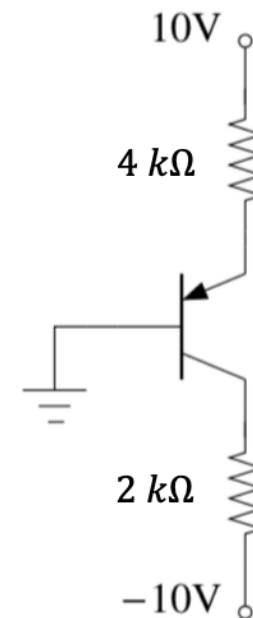
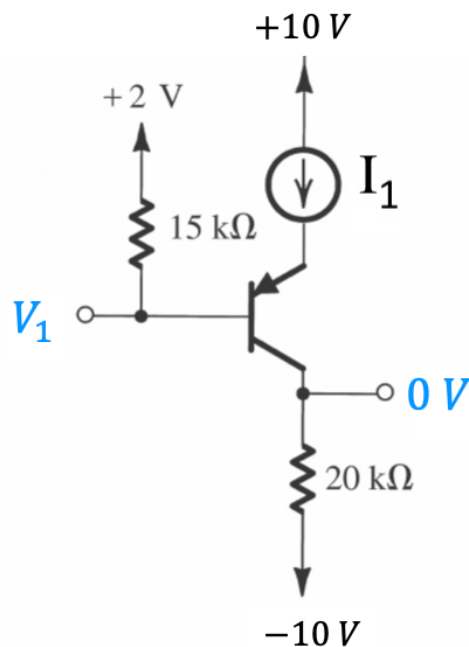
## 3. Bipolar Junction Transistor (BJT)



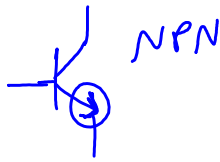
## Note:

In the BJT and MOSFET circuits, to differentiate the applied node voltages from the measured node voltages:

We will show the measured node voltages in **blue color** and the DC or AC voltage sources connected to different nodes in **black color**.



## PNP Transistor Example:



In this circuit, find the transistor parameters (Si BJT with  $\beta = 100$ ).

EB KVL:

$$12 = V_{EB} + 40k \times i_B + 8$$

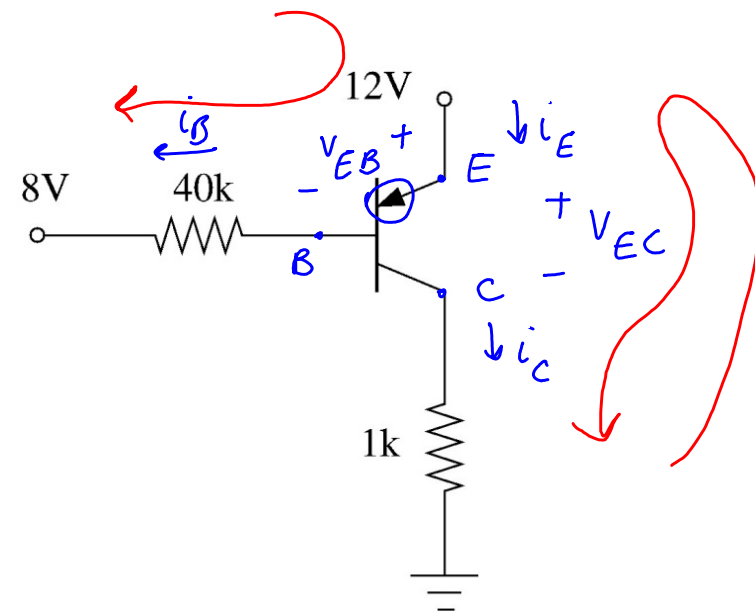
$$4 = V_{EB} + 40k \times i_B$$

EC KVL:

$$12 = V_{EC} + 1k \times i_C$$

Assume the BJT is in cut-off,  $i_B = 0$ ,  $V_{EB} < V_{D_0} = 0.7V$

EB KVL:  $4 = V_{EB} + 40k \times 0 \rightarrow V_{EB} = 4V > 0.7 \rightarrow$  BJT is not in cut-off



BJT is ON,  $i_B \geq 0$ ,  $V_{EB} = V_{D_0} = 0.7 \text{ V}$

EB KVL,  $4 = 40\text{k} \times i_B + 0.7 \rightarrow i_B = 82.5 \mu\text{A} > 0$

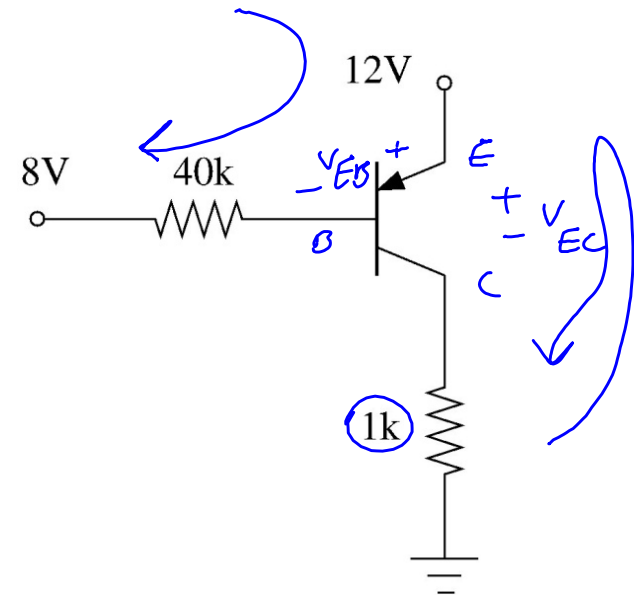
Assuming active mode:

$i_C = \beta i_B$ ,  $V_{EC} \geq V_{D_0} = 0.7 \text{ V}$

$i_C = 100 \times 82.8 \mu\text{A} = 8.25 \text{ mA}$

EC KVL:  $12 = V_{EC} + \underbrace{10^3}_{1\text{k}} \times \underbrace{8.25 \times 10^{-3}}_{8.25 \text{ mA}} \rightarrow \underline{V_{EC} = 3.75 \text{ V}} > 0.7$

Assumption was correct, BJT is in active mode.



# Lecture 11 reading quiz

Find the transistor parameters in this BJT circuit. ( $\beta = 100$ ,  $V_{D0} = 0.7V$ ).

Assume cut-off:  $i_B = 0$ ,  $V_{EB} < V_{D0}$

BE-KVL:  $15V = V_{EB} + 220k \times i_B$

with  $i_B = 0 \rightarrow V_{EB} = 15V > 0.7V \rightarrow$  BJT is ON

$V_{EB} = 0.7V$ ,  $i_B \geq 0$

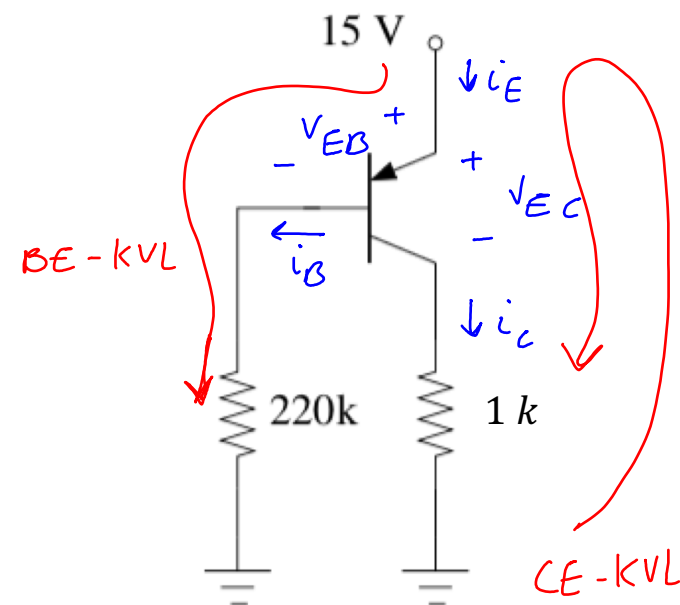
BE-KVL:  $i_B = \frac{15 - 0.7}{220k\Omega} = 65\mu A$

Assume active mode of operation:  $i_C = \beta i_B$ ,  $V_{EC} \geq V_{D0}$

$i_C = 100 \times i_B = 6.5mA$

CE-KVL:  $15V = V_{EC} + 1k \times i_C \rightarrow V_{EC} = 15V - 1k \times 6.5mA = 8.5V > V_{D0}$

Assumption was correct,  $i_C = 6.5mA$ ,  $i_B = 65\mu A$ ,  $V_{EC} = 8.5V$ ,  $V_{EB} = 0.7V$



## Clicker question 1:

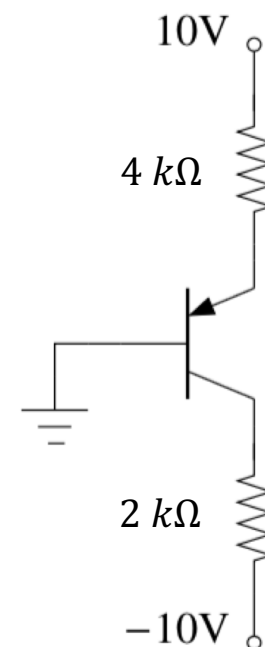
The transistor in the following circuit has  $\beta = 100$ . Find the value for  $V_{EC}$ . ( assume  $V_{D0} = 0.7V$ ,  $V_{sat} = 0.2 V$ ).

A.  $V_{EC} \approx 10.5 V$

B.  $V_{EC} = 0 V$

C.  $V_{EC} \approx 6.1 V$

D.  $V_{EC} = 0.2 V$



**Cut-off :**

$$i_B = 0, \quad i_C = 0$$

$$v_{EB} < V_{D0}$$

**Active:**

$$v_{EB} = V_{D0}, \quad i_B \geq 0$$

$$i_C = \beta i_B, \quad v_{EC} \geq V_{D0}$$

**Saturation:**

$$v_{EB} = V_{D0}, \quad i_B \geq 0$$

$$v_{EC} = V_{sat}, \quad i_C < \beta i_B$$

Assume BJT is in cut-off  
 $i_B = 0, i_C = 0, i_E = 0, V_{EB} < 0.7V$

$$i_E = i_C + i_B$$

EB KVL:  $10V = 4k\Omega \times i_E + V_{EB}$

$V_{EB} = 10V > 0.7V \rightarrow$  Assumption was wrong

BJT is ON,  $V_{EB} = 0.7V, i_B \geq 0$

Assume BJT is in active region:

$i_C = \beta i_B, V_{EC} \geq V_{D_0}$

EB KVL:  $10V = 4k\Omega \times i_E + 0.7V \rightarrow i_E = \frac{9.3V}{4k\Omega} = 2.325mA$

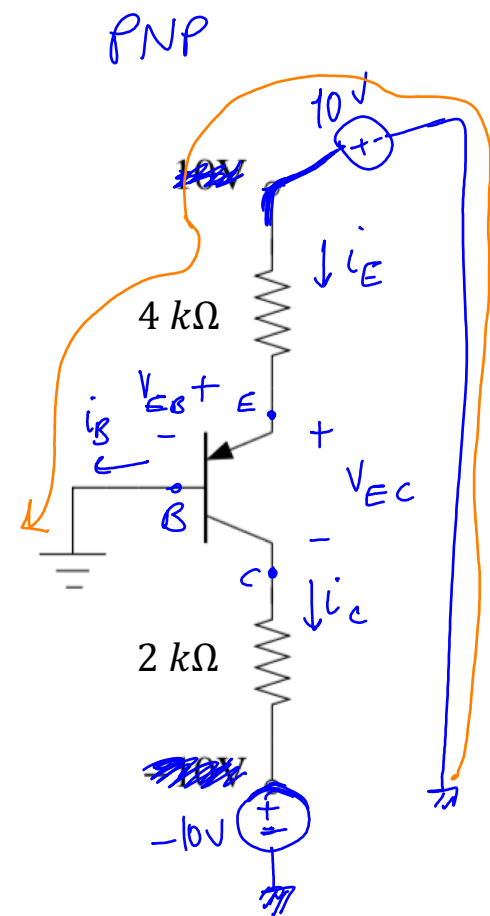
EC KVL:  $10V = 4k\Omega \times i_E + V_{EC} + 2k\Omega \times i_C - 10V$

$20V = 4k\Omega \times i_E + 2k\Omega \times i_C + V_{EC}$

$20V = 4k \times 2.325mA + 2k \times 2.3mA + V_{EC} \rightarrow V_{EC} \approx 6.1V > 0.7$

$i_C = \beta i_B \rightarrow i_B = \frac{1}{\beta} i_C$

$i_C + i_B = i_E \rightarrow i_C + \frac{1}{\beta} i_C = i_E \rightarrow i_E = \frac{\beta + 1}{\beta} i_C \rightarrow i_C \approx 2.3mA$



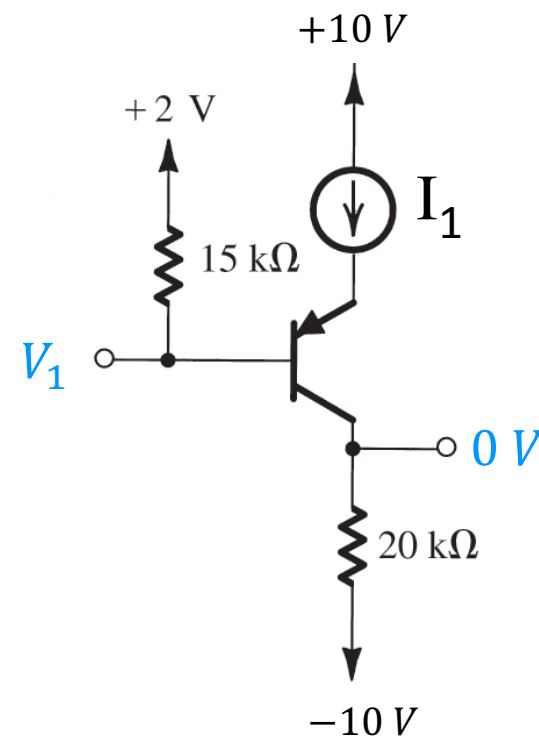


$$V_{EC} = 6.1 \text{ V} > 0.7 \text{ V}$$

assumption was correct.

## Discussion question 1:

In this BJT circuit find  $V_1$  and  $I_1$ . Assume  $\beta = 100$ ,  $V_{D0} = 0.7V$ ,  $V_{sat} = 0.2V$ .



### Cut-off :

$$i_B = 0, \quad i_C = 0$$

$$v_{EB} < V_{D0}$$

### Active:

$$v_{EB} = V_{D0}, \quad i_B \geq 0$$

$$i_C = \beta i_B, \quad v_{EC} \geq V_{D0}$$

### Saturation:

$$v_{EB} = V_{D0}, \quad i_B \geq 0$$

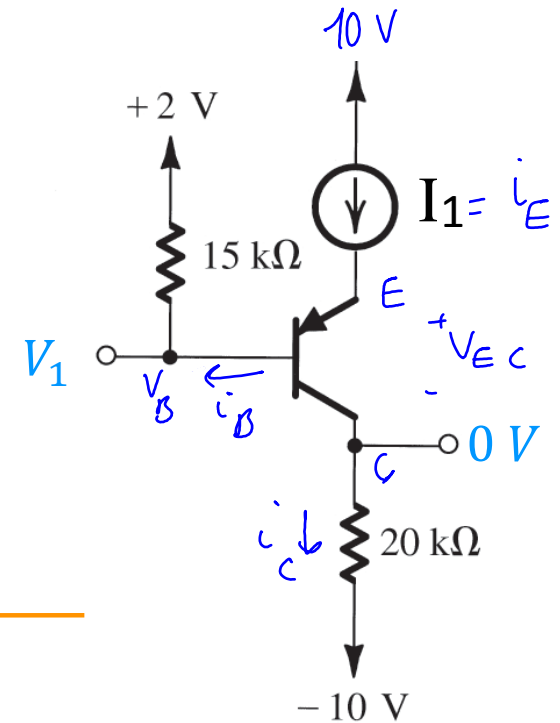
$$v_{EC} = V_{sat}, \quad i_C < \beta i_B$$

$$i_c = \frac{0 - (-10V)}{20k\Omega} = 0.5mA \rightarrow \text{BJT is ON}$$

Assume active mode:

$$i_B = \frac{i_c}{\beta} = 5 \mu A$$

$$i_E = I_1 = 0.505mA$$



$$V_B = V_1 = 2V + 15k \times i_B = 2.075V$$

$$\text{BJT is ON} \rightarrow V_{EB} = 0.7 = V_E - V_B = V_E - 2.075 = 0.7V$$

$$\rightarrow V_E = 2.775V$$

$$V_{EC} = V_E - V_C = 2.775 - 0 = 2.775V > V_{D_0} \quad \checkmark$$

Assumption was correct.